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Nitrogen impurities and fluorescent NV⁻ centers in detonation nanodiamonds: identification and distinct features

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Abstract

We show that nitrogen is the main impurity contained in detonation nano-diamonds (DNDs), at a concentration of ~16000 ppm. The content of nitrogen-vacancy (NV⁻) centers in these DNDs is ~2.7 ppm, which is the largest of all known types of nano-diamonds of size <10 nm with artificially created NV⁻ centers. The removal of graphite-like fragments from the DND surface allowed us to detect the characteristic photoluminescence (PL) of the NV⁻color centers in individual DND aggregates of sizes from 50-100 to 500-700 nm. We have further confirmed the detection of the negatively charged NV⁻ through the observation of a strong decrease in the PL intensity when an external magnetic field is applied. Such an effect results from the optically detectable magnetic resonance of the electronic spin triplet ground state of NV⁻, that cannot be observed in other emitting defects, in a similar spectral range, including the neutral NV⁰ centers.

Codes OCIS: (160.4236) Nanomaterials; (160.2540) Fluorescent and luminescent materials; (300.6280) Spectroscopy, fluorescence and luminescence; (300.6370) Spectroscopy, microwave; 240.6675 (Surface photoemission and photoelectron spectroscopy), 280.1545 (Chemical analysis), (350.3850) Materials processing

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1. Introduction

Fluorescent micro- and nanodiamonds (NDs) containing NV⁻ centers are novel objects that have a number of promising innovative applications in magnetic sensing [1,2], cellular imaging and sensing [3], optical telecommunications [4], and quantum information processing [5]. This wide range of applications arises from the unique properties of the negatively charged NV⁻ color centers with triplet spin properties that can be detected optically (Optically Detectable Magnetic Resonance, ODMR) [6] and great potential use of nanodiamonds (size <40 nm) in advanced biomedical applications [7-9]. The use of NV⁻containing ultra-small detonation nanodiamonds (DND, size < 6 nm) in magnetic sensing applications at the nanoscale is still questioned due to a high concentration of various defects and imperfections in such nanocrystals [10]. Indeed, DNDs are formed during the process of detonation of a mixture of trinitrotoluene and hexogen under conditions of negative oxygen balance [11]. Synthesis is carried out in a very short time- on the order of microseconds. During this time, diamond crystallites up to 5 nm in size, with characteristically high levels of defects, are self-assembled from the decomposition products of the explosive mixture components- *i.e.* predominantly carbon. The details of the synthesis have been extensively described in the literature [11]. Nitrogen, which is one of the constituent elements of the components of the explosive mixture, also incorporates into the diamond lattice during the synthesis. It readily diffuses within the lattice structure, replacing carbon atoms, resulting in the existence of unpaired antibonding electron orbitals, which in turn gives rise to the S = 1/2paramagnetism of the nitrogen-doped diamond crystal. In principle, nitrogen impurities can reside in a diamond lattice in a variety of forms - an isolated neutral state (C or P1 centers), a dimerized form (pairs of nitrogen atoms located at adjacent lattice sites: A centers) and numerous nitrogen-vacancy clusters, consisting of different numbers of nitrogen atoms and vacancies. The most important clusters, known for most types of synthetic and natural diamond crystals, include NV, NVN and 4NV centers. The latter, for example, represents four substitutional nitrogen atoms in a tetrahedral environment around a central vacancy. NV and NVN centers cause bright and stable fluorescence of diamonds in the red and green regions of the spectrum respectively. These centers can be purposefully induced in diamond crystals with nitrogen doping concentrations up to ~ 200 ppm by irradiation with high-energy (2-15 MeV) electrons, creating vacancies in the diamond lattice, and by the subsequent annealing- at temperatures \approx 800-950 °C, which makes the vacancies mobile and allow their capture by substitutional nitrogen atoms [12]. As a result, NV and NVN centers appear in the

diamond lattice. In detonation diamonds, vacancies are naturally present as results of stacking faults and inaccuracies that occur during the rapid assembly of a diamond lattice from CH_3^* radicals, which are detonation products after pyrolysis. Therefore, in addition to nitrogen impurities, DND particles also contain isolated vacancies, multivacancies and NV type defect centers [10].

Multivacancies and NV⁻ centers were successfully identified in DNDs by the method of electron paramagnetic resonance (EPR) in recent works of the authors [13-15]. Although certain EPR signals in DNDs were recorded back in 2002-2003, at the beginning of extensive research of this material, it took almost 10 years to understand and correctly assign them via exclusion of all possible parasitic factors associated with the impurity background and other types of incurred defects [13]. Moreover, studies combining different analysis methods, including: EPR spectroscopy, Raman spectroscopy, confocal fluorescence spectroscopy and X-ray photoelectron spectroscopy (XPS), have not been focused to date on the topic of NV centers within DNDs. In this work, we report results on the first complete investigations of DND particles that demonstrate specific photoluminescence (PL) of NV⁻ centers in DND, and also their sensitivity to an external magnetic field, related to their unique ODMR property.

2. Experimental

2.1. Fabrication Methods

DND powders were obtained by standard technology which includes blasting of an explosive mixture of trinitrotoluene-hexogen under conditions of negative oxygen balance. Synthesis and primary purification of the product was carried out by the commercial manufacturer the Federal State Unitary Enterprise "SCTB" Technolog " and the Ioffe Physical-Technical Institute, St. Petersburg, Russia. The unique technological process for powder synthesis offered by this manufacturer, made it possible to obtain diamond nanoparticles with a coherent scattering area size slightly exceeding 5 nm. The X-ray powder diffraction (XRD) study demonstrated a coherent scattering size of selected sample of synthesized diamond nanoparticles up to 5.6 nm.

The DND powders were further purified in acid mixtures to remove residual impurities of 3d ferromagnetic metals for more accurate EPR and XPS studies. An additional surface cleaning by annealing of the DND powders in air at 430° C for 10-12 hours was required for Raman scattering and subsequent photoluminescence studies [16]. For Raman

studies samples were prepared by "pressing powder" into a cylinder of 3 mm in diameter and of no more than 2 mm thick inside a stainless steel cage.

Samples for confocal fluorescence microscopy studies were fabricated from the DNDs aqueous suspensions, that were readily obtained by dispersing the annealed powder in water at a concentration of ≈ 1 mg/mL. The DNDs suspensions were diluted in water by a factor of 100 and spincoated onto a 170 µm thick glass coverglass (Nexterion, Schott, Germany), which was precleaned in a mixture of ethanol and acetone in ultrasonic bath. Finally, for an accurate photoluminescence study, DND aggregates deposited on coverglass substrates were cleaned with a UV/O-Cleaner (low pressure mercury vapor grid lamp: 28,000 µW/cm² at 254 nm wavelength; model 42-220 from Jelight, USA) for 15 minutes. Under UV light exposure the process of efficient oxidation of graphite-like *sp*² phase around the DNDs with oxygen and/or ozone occurs, which is followed by gas-phase etching of the surface with substantial removal of *sp*² carbon. The nanostructured *sp*²-carbon absorbs optical radiation and, therefore, is extremely undesirable for PL investigation from DND particles. Exposure of the substrate with deposited DND particles to UV radiations also leads to the removal of the parasitic organic compounds, which can create some luminescent background.

2.2. Characterization Methods

2.2.1. Electron paramagnetic resonance (EPR)

The EPR spectra of the samples were recorded at room temperature within the microwave X-band at a frequency of ~ 9.5 GHz using EPR spectrometer JEOL JES-FA 300 (Japan). Powder in the amount of 50-60 mg was introduced into a EPR quartz tube of 4 mm in diameter. The height of the powder column in the tube did not exceed 10 mm. The open end of the tube was sealed against moisture.

The EPR spectra with g-factors in the range 4.00-4.30 were recorded with microwave power of $P_{\rm MW} = 10$ mW, magnetic field modulation amplitude $A_{\rm m} = 10$ G and frequency v = 100 kHz, the gain, $G \sim 10^3$, and the signal accumulation N = 16. These parameters were chosen to obtain the optimal signal-to-noise ratio. The time constant was 0.030 s, the total recording time for the magnetic field sweep in interval from 1300 to 2000 G was 120 seconds. At microwave power $P_{\rm MW} < 50$ mW, the intensity of the EPR signal with the g-factor $g \approx 4$ followed a linear dependence of $I_{\rm PP} \sim (P_{\rm MW})^{1/2}$ and there was no signal distortion from saturation. The concentration of paramagnetic NV⁻ centers was estimated by double integration of the corresponding EPR signal with g = 4.26, followed by assignment to

the corresponding sample weight and comparison to the reference EPR signal(s) from reference sample(s). We chose one reference DND sample with well-defined integrated intensity of the g = 2.0027 EPR line and with previously independently determined S = 1/2 paramagnetic center's concentration of 6.3×10^{19} centers/g (1260 ppm) by precision measurements of the magnetization field dependence at low temperatures using a SQUID¹ magnetometer. In addition, a synthetic fluorescent Ib HPHT diamond powder with calculated integral intensity of the g = 4.26 EPR line and known concentration of S = 1 NV⁻ centers of 5 ppm was also used as an independent reference for correct determination of the obtained concentration of NV⁻ in DND [17]. The EPR g=4.26 line was recorded for this reference sample with the following parameters: $P_{MW} = 1 \mu W$, $A_m = 1.6$ G, N = 25 in a mode far from saturation.

2.2.2. X-ray photoelectron spectroscopy (XPS)

X-ray photoelectron spectroscopy (XPS) of DNDs was performed using Perkin-Elmer PHI 5600 Multi-Technique system, equipped with a source of monochromatic Al Ka radiation (photon energy 1486.6 eV) and a hemispherical energy analyzer. The angle of incidence of X-rays on the sample was 45 °. The spectral characteristics² of photoelectrons were obtained after analyzing of photoelectrons flux emitted with different kinetic energies from a sample area of $\sim 1 \text{ mm}^2$ [18]. Detected photoelectrons are emitted by the material surface- a few atomic layers thick top layer (no more than 5-10 nm). Particular attention was paid to analyses of the areas of photoemission peaks of carbon C1s, nitrogen N1s and oxygen O1s. Obtained spectral characteristics were processed in MultiPak v8.2. Decomposition of photoemission peaks into individual components (contours) was performed after subtraction of the background followed by approximation of the shape of the peaks by a set of Gaussian or mixed-type singlet contours. Spectra of the DND sample were taken before and after etching of the surface with argon ions. Ion etching was carried out for 3 minutes at an accelerating voltage of 3 kV and an ion beam current of about 4 µA. The Ar ion etching was used not only for cleaning of the sample surface from adsorbed gases and other chemisorbed atomic complexes, but also to study composition and distribution of elements covalently bonded to diamond surface. Charging effect during measurements was eliminated by electron beam irradiation of the samples.

¹ Superconducting quantum interference device

² The number of detected electrons emitted in a single energy interval, depending on their kinetic energy.

2.2.3. Raman scattering

Spectra of secondary radiation, i.e. luminescent radiation together with Raman scattering, were collected using 532 nm (power 0.5 mW) and 325 nm³ (power 0.8 mW) excitation laser wavelengths of a home-built micro-Raman system. Secondary radiation was collected in the backscattering geometry with laser spot of diameter ~ 2 μ m focused on the surface of sample using 50× microobjective for 532 nm excitation wavelength and using specially designed UV microscope lens with 30-36 accumulations for 325 nm excitation wavelength. In studies using both excitation lasers, diffraction gratings with grooves densities of 600 mm⁻¹ (532 nm laser) and 1800 mm⁻¹ (325 nm laser) were used.

2.2.4. Confocal fluorescence microscopy

The PL setup used to map PL from DND particles spincoated on coverglass consists of a home-made inverted confocal scanning microscope combined with an imaging spectrograph. The confocal microscope includes a piezoelectric scanning stage (NanoPDQ75, Mad City Labs Inc., USA), a high-numerical aperture microscope objective (PlanApo 100×, NA=1.40, Nikon, Japan), an optically pumped semiconductor laser (Verdi, Coherent Inc., USA) emitting at 532 nm wavelength that is injected into the objective through a long-pass interferential dichroic mirror (z532rdc, Semrock, USA). After a 50 µm diameter confocal pinhole, a bandpass filter (FF01-697/75, Semrock) is inserted on the detection path to reject the remaining excitation light. A single photon counting module (SPCM-AQR-14, Perkin-Elmer, Canada) is used as a point detector. The excitation radiation from laser is circularly polarized and has the power of 0.5 mW. The imaging spectrograph is composed of a concave grating imaging the spectrum on a back-illuminated cooled CCD silicon array detector (DU440-BU2, Andor Technologies, UK), leading to a spectral resolution of about 1 nm.

Mapping of the luminescence signal was carried out in a square of $20 \times 20 \ \mu\text{m}^2$. To remove the PL spectrum in the range of 500-900 nm, one of several DND aggregates deposited on the substrate (within the light spot of the microobjective of 100×) with transverse dimensions of only 0.6 microns and having intense luminescence was selected. The exposure time was 60 s including the removal of one spectrum. The magnetic field was

³ Excitation wavelength of 325 nm was used only for Raman spectroscopy measurements of detonation diamond. In this case, the contribution to Raman scattering signal from collective defects of the graphite-like sp^2 phase is significantly reduced in the region 1350-1400 cm⁻¹ (so-called *D* band), and the sample luminescence is also suppressed comparing with the case of 532 nm excitation.

applied using an iron-neodymium-bore doped permanent magnet brought at a few millimeters distance to the coverglass sample. Its magnitude at the sample location was about ~900 G. The time dependence of the luminescence signal was recorded with repeated exposure and removal of the magnet.

3. Experimental results and discussion

3.1. Identification of NV⁻ centers in DND and measurement of their concentration

Since the radiation emitted by centers can be absorbed by neighboring absorbing agents and phases surrounding the particles (e.g. graphitic coverage and metal inclusions), it is very important to control and monitor NV⁻ centers in diamonds by non-optical methods independently. The negatively charged NV⁻ centers can be detected by EPR spectroscopy even in case of absence their photoluminescence and their total concentration can be easy evaluated by analysis the EPR spectrum [14,19,20]. At the same time, the evaluated total NV⁻ centers concentration provides valuable information on the potential brightness of NV⁻ PL after extensive purification. The EPR spectrum of the DND powder purified from 3dtransition metal magnetic impurities (mostly Fe, Ni) in the region of the so-called half magnetic field corresponding to g-factor $g \sim 4$ is shown in Fig 1. The spectrum consists of two close lines with g-factors $g_1=4.26$ and $g_2=4.00$, and widths $\Delta H_{pp1}=28$ G and $\Delta H_{pp2}=$ 13.5 G. The distance between the lines is about 100 G. The first low field line, corresponds to the forbidden transitions $\Delta M_s=2$ between the Zeeman energy levels of the triplet state of the NV⁻ center in a magnetic field, and the second, high-field, to the same forbidden transitions $\Delta M_s=2$, which occurs when microwave radiation is absorbed by multivacancies. In ref. 14 these lines were assigned to triplet centers in the DNDs, and in particular the g_1 =4.26 line was assigned to NV⁻ center. The position of this $g_1=4.26$ line is highly sensitive to the microwave frequency, and can be shifted by $\sim 0.5\%$ upon a small frequency change from 9.0 to 9.9 GHz (X-band). This sensitivity is due to the large value of the zero-field splitting parameter D ($D=850\times10^{-4}$ cm⁻¹), which is related to the exchange interaction of constituting spins in the spin Hamiltonian of the triplet center [19]. The position of the second line $(g_2=4.00)$ is practically independent to frequency changes, and the parameter D of the corresponding triplet center (multivacancy) is approximately 5-6 times smaller. The integral intensity of the line $g_1 = 4.26$ can be used to precisely estimate the concentration of NV⁻ centers even when the luminescence of nanodiamonds is not detectable due to absorption by graphite-like atomic shells. Using a synthetic submicron diamond with a known

concentration of NV⁻ centers as a reference sample, the concentration of NV⁻ centers in the DNDs was determined to be 2.7 ppm. Additionally, we found that main technological treatments at temperatures below 500 °C (in vacuum, in air and even in fluorine gas) have no effect on the concentration of NV⁻ centers in the DNDs. This is because the EPR spectrum of DND in the half-magnetic field region is practically not changed and has almost the same double integrated intensity of signal g_1 =4.26 after described treatments. This indicates that the NV⁻ centers are buried from the nanoparticle surface at least by the lattice constant (~0.36 nm) and are not in reaction with most of external chemical agents that do not etch the diamond phase. Only high temperature treatment at 900-1000°C leads to disappearance of the NV⁻ centers due to their significant modification or unification into larger aggregates and complexes due to the diffusion of vacancies.

The main EPR signal of the DND has a Lorenzian curve profile of linewidth $\Delta H_{pp}=8.4 \text{ G}$ [13] wider than the one of fluorescent nanodiamonds (FNDs) milled from microcrystalline diamond synthesized by high pressure and high temperature (HPHT) method. This broad signal can be explained by more larger exchange and dipole-dipole interactions between the spins S=1/2 in spin ensemble within individual DND nanoparticle than within FND. The dipole-dipole interaction between spins is inversely proportional to the third power of the distance between them and does not depend on the medium (vacuum or solid). The intensity of the main EPR signal collected from all paramagnetic centers S=1/2, both of nitrogen (P1 centers [21]) and non-nitrogen origin, indicates a spin concentration of ~1300 ppm, corresponding¹ to ~ 15 of S=1/2 spins in each DND [13]. The exchange interaction neutralizes the individual features of different interior spins 1/2, erases the difference between them and the consolidated Lorentzian ESR signal of g=2.0027 indicates paramagnetic centers of pseudo-single origin. However, it can be concluded from obtained data that approximately 40-50% of the total number of all paramagnetic centers in the DNDs is due to unpaired antibonding orbitals of isolated nitrogen dopants (P1 centers). The experimental concentration estimate of NV⁻ centers in the DNDs is approximately ~500 times smaller than the concentration of all S=1/2 paramagnetic defects in the system, and approximately 220 times smaller than the estimated concentration of isolated nitrogen atoms.

This concentration ratio for isolated paramagnetic nitrogen (P1) and NV⁻ centres is qualitatively consistent with the process of NV center formation: from "randomly built-in"

¹ We assume that each DND consists of ~ 11,000 carbon atoms.

during the ~ 0.5 μ s duration of the synthesis to the growing diamond nanoparticle volume both substitutional nitrogen atoms and vacancies. Here, we assumed that each NV⁻ center is formed as a result of random occurrence of substitutional nitrogen atoms and vacancies in the nearest neighbour lattice sites during detonation synthesis and subsequent rapid cooling to temperatures of the order of ~500 °C. Thus, the diffusion range of vacancies in the lattice during such short synthesis does not exceed few nanometers.

3.2. Determination of Nitrogen Impurities Concentration

The complete understanding of the DNDs composition (both surface and bulk) requires the knowledge of concentration of all impurities, which can be precisely determined using X-ray photoelectron spectroscopy (XPS). XPS is a powerful tool for studying the chemical state of main alien elements in bulk and on the surface of the DNDs [22]. The XPS signals of carbon (C1s), oxygen (O1s) and nitrogen (N1s) have been recorded before and after etching of the surface with Ar ions. The data indicate the presence of oxygen-containing atomic groups - hydroxyl, carboxyl and carbonyl groups at DND surface. The concentration of surface oxygen and inner nitrogen was determined to be ~5.5 at% and ~1.6 at% respectively. In addition to these elements, photoemission signals from Silicon (Si2p), Titanium (Ti2p), Aluminium (Al2p) were also recorded, but the concentration of the first two did not exceed 0.1 at. %, and the aluminium concentration was 0.21 at.% [23]. However, our main interest was focused on the XPS signal from nitrogen, since nitrogen is a main inner impurity. The photoemission peak of nitrogen (N1s) before and after etching by Ar ions is shown in Fig.2. Etching with Ar ions (accelerated to 3 keV energy) for 3 minutes results in the removal of weakly bound chemical sorbents and physically adsorbed compounds from the surface, while the diamond covalent lattice remains not affected. The characteristic highenergy peaks (404.9 eV and 407.3 eV) strongly decrease or even disappear in N1s photoemission signal after Ar ion etching, which demonstrates presence of nitrate-ions and nitrite-groups on the untreated surface. At the same time, the strong decrease of the N1s peak at ~ 407 eV in the XPS spectral characteristics indicates complete or partial removal of nitrate-ions from the surface (Fig.2b). In fact, nitrate-ions are chemical sorbents bound to the surface through defective sites. They are formed at the stage of synthesis and chemical purification of DNDs from graphite-like phase in nitric acid. In Fig.2b the peak at ~405 eV is suppressed only partially, which indicates that even after Ar ion etching there is a stronger bond between the corresponding nitrite groups and the surface. The main peak of N1s signal

at ~401 eV, remains after ion beam treatment and corresponds to chemical bonds of the type N-sp³-C. This peak is a main characteristic of nitrogen impurity elements covalently bound to the diamond lattice. This peak signal appears due to all forms of nitrogen present in the diamond matrix, including NN nitrogen dimers, next nearest neighbouring or distant, farlying NN pairs, and more complex clusters of few nitrogen atoms. It is worth to note, that the photoemission peak N1s in the low-energy region at ~ 398-399 eV, which usually corresponds to the covalent bonds of nitrogen with carbon in the sp^2 hybridization of N- sp^2 -C, is not present in the XPS spectrum. This indicates both a very small amount of carbon in the sp^2 coordination on the surface of DNDs, and a significant localization of nitrogen in sp^3 crystalline lattice within diamond nanoparticles. Similar data were obtained for the photoemission peak of carbon C1s (see Ref. 23 for details). After ion etching, this signal consists of two main peaks: the one centred on 284.9 eV corresponds to C-C bonds in diamond matrix, and the peak centred on 287.3 eV to chemical bonds C-N. The C1s peak at 288.6 eV, which corresponds to carbon in the carboxylic groups, disappears after ion etching: only diamond carbon and sp^3 carbon bound to nitrogen remains in the C1s signal. Our complex XPS analysis of N1s and C1s signals (together with O1s, Al2p and residual elements (<0.1 at.%) signals) suggests that nitrogen is contained within the diamond lattice in an amount up to 1.6 at% (~ 16000 ppm) and mainly in the form of complex clusters which are not paramagnetic like dimers NN (A-centers) and therefore not EPR observable. A small part of these clusters represents isolated paramagnetic nitrogen atoms with spin S=1/2 and is accessible for observation by EPR. The total amount of paramagnetic nitrogen in the neutral state does not exceed ~1300 ppm according to the EPR data, *i.e.* 9% of all forms of nitrogen recorded in diamond lattice according to XPS data.

3.3. Identification of diamond lattice from Raman spectrum

Independent identification of crystalline diamond phase in DNDs was performed from Raman analysis extracted from the spectra of secondary radiation after subtracting the luminescent background. The DND PL spectrum recorded with excitation wavelength of 532 nm demonstrates a strong NV^- center emission band in the interval 600-750 nm, and badly distinguishable characteristic Raman bands for diamond and graphite phases in the spectral interval <600 nm (PL and Raman spectra obtained at 532 nm excitation are not presented here). The effective analysis of the weak Raman lines under 532 nm excitation wavelength is difficult due to strong luminescence background, while the subtraction of

which reveals a large noise level in the Raman signal. The characteritic Raman peaks of DNDs (actual diamond peak at ~1323 cm⁻¹ with FWHM = 36 cm^{-1} and graphite G peak at ~1590 cm⁻¹) are obtained at resonant excitation of 325 nm for which the PL is reduced (Fig. 3). The Lorenz or Gaussian approximation applied to obtained experimental spectra allows to observe a band at 1299 cm⁻¹ which overlaps the characteristic Raman band of 1323 cm⁻¹ attributed to diamond lattice of finite length (<5 nm), and with a FWHM ~ 220 cm⁻¹ ¹ much wider that the one of the 1323 cm⁻¹ line. This 1299 cm⁻¹ wide band can be attributed not only to amorphous carbon in a state of sp^2/sp^3 hybridization, but also to some fraction of fine diamond particles with a size of less than 2-3 nm [24,25]. Following Ref. 26 the highfrequency band at ~1650 cm⁻¹ can be attributed to Raman scattering by bending vibrations of surface O-H groups or even water molecules adsorbed on DND particles. All main Raman bands attributed to diamond lattice of few nanometer length, to graphite-like sp^2 phase, or to hydroxyl groups and physisorbed water at the sample surface are characterized by intensities of about the same order. However, the scattering cross-section of diamond and graphite phases differ by more than 50 times, which makes it impossible to quantitatively estimate the content of the graphite sp^2 phase in the material by this method. In accordance with other methods, e.g. nuclear magnetic resonance, the graphite phase content should not exceed $\sim 6-8$ at.% [27]. This is achieved by exposure of the material to air at 430°C for several hours. As a result, the gas-phase decomposition and removal of the sp^2 shell partially covering the DND surface occur. Removing sp^2 shells by gas-phase etching in air is a prerequisite for obtaining intense luminescence from NV⁻ centers in DNDs. Thus, the presence of diamond Raman peak at ~ 1323 cm⁻¹ with FWHM = 36 cm⁻¹ confirms the good crystalline quality of DND particles with size about 5 nm.

3.4. Confocal fluorescence microscopy and local probing sensitive to magnetic field.

Registration of fluorescent radiation emitted by isolated DND particles or aggregates is crucial for understanding their potential use as fluorescent markers and nanosensors. Photoluminescence was recorded on DND aggregates spin-coated on a glass microscope coverslip. The average size of DND aggregates in the aqueous suspension before spin-coating was 30 nm (as measured by dynamic light scattering).

Figure 4a shows a PL 2D map obtained by confocal microscopy, using a 532 nm wavelength excitation laser. Bright spots corresponding to aggregates of DNDs particle up to 500-800 nm in size are observed, among dimmer spots of size limited by optical diffraction, corresponding to aggregates of smaller dimensions (in the range 50-100 nm). Obviously, the

larger in size DND aggregates, contain higher number of luminescence centres (NV⁻ defects), because the PL intensity is approximately 7-8 times greater than the one of aggregates of smaller size. The PL spectrum of the aggregate surrounded by circle in Fig. 4a is shown in Fig. 4b. It indicates the presence of both NV⁻ and NV⁰ defects, although their characteristic zero-phonon lines (ZPL) at 638 nm and 575 nm respectively are not detected. ZPLs are usually well resolved only for diamond crystals of micron size or larger, while for nanometerscale crystals it is usually not observed, due to quantization and subsequent substantial distortion of phonon modes. This effect is analogous to Raman line broadening upon transition from single crystals diamond to diamond nanoparticles of <5 nm in size. To confirm unambiguously the presence of NV⁻ centers and not only of NV⁰ in the DND, we studied the influence of an external magnetic field on the PL intensity. No PL modification is expected from NV⁰, which has no magneto-optical properties contrary to NV⁻. Figure 5 shows the time variation of the PL intensity from an isolated DND aggregate in the presence of an external magnetic field switch on by quickly approaching a compact permanent magnet from the DND ("ON", $\boldsymbol{B} \neq 0$) or by removing it ("OFF", $\boldsymbol{B} = 0$). The PL time dependence has a square "telegraph-like" form due to the decrease of PL intensity when the magnetic field is applied (amplitude ~900 G). This occurs as a result of mixing the $m_s = 0$ and $m_s = \pm 1$ sublevels of the NV⁻ centers and a corresponding change in their populations with magnetic field being "ON". More precisely, the NV⁻ ground and excited states have a triplet symmetry, with the spin quantum number $m_S = 0,\pm 1$ quantized along the N-V axis in the crystal. The optical transitions between the ground and excited triplet states preserve the spin state (Δm_s =0). However, from the $m_s = \pm 1$ excited state, NV⁻ also decays with no radiation in the visible domain, through a system of two singlet metastable states before coming back to the ground state [6]. This additional decay pathways results in a lower fluorescence intensity from transition within the $m_s = \pm 1$ subsystem of ground and excited triplet states, than within the ms=0 subsystem, which is also at the origin of the ODMR signal. Incidentally, the same pathway is also responsible for the spin ground state polarization in the $m_s = 0$ sub-state, under optical pumping at 532 nm wavelength. Moreover, in an external magnetic field B, the energy degeneracy between $m_s = \pm 1$ levels is lifted and the ground and excited spin states $|m_{s}\rangle$ can be decomposed on the $|0\rangle$ and $|\pm 1\rangle$ basis. The coefficients of such linear combination are determined by the external magnetic field amplitude and direction and can be calculated from the NV⁻ spin Hamiltonian in the **B** field. In the general case $|m_S\rangle$ is a mix of $|0\rangle$ and $|\pm 1\rangle$ [28]. Therefore, compared to the situation of pure $|0\rangle$ state that results from optical pumping under 532 nm light excitation (and in absence of B), a decrease of NV⁻ center fluorescence intensity is expected in the presence of an external magnetic field [29], as observed in Fig. 5.

4. Conclusion

In this article, we have shown that nitrogen is the main impurity in the DNDs. It is contained in the crystalline lattice of diamond in an amount of ~16,000 ppm. The content of NV^{-} centres is ~2.7 ppm, which is the largest ever detected in this types of nano-diamonds of size <10 nm. The ultra-small dimensions cause NV⁻ luminescence quenching and absorption of emitted radiation by various point and collective defects located near the surface. Annealing treatment of DNDs in air and/or in ozone allows to remove such defects associated to graphite-like fragments at DND surface and to detect the specific PL of NV⁻ centres, both in DND powder and in individual DND aggregates. When an external magnetic field is switched "ON" and "OFF", an accompanying variation of the PL intensity is observed, which results from the sensitivity of the NV⁻ triplet ground state to magnetic field and from the optically detectable magnetic resonance characteristic of this NV charge state only. The application of this effect to discriminate ultra-small DND (size<10 nm) in biological environment with large autofluorescence background (for enhancement the contrast of intercellular imaging) is promising [30]. Such DND could also be used as point optical probes of high resolution nanoscale magnetic field sensing and all-optical magnetic imaging [31].

Figure captions.

Fig.1. EPR spectra of acid-purified DNDs in the region of half magnetic field (blue curve) and of reference fluorescent Ib HPHT diamond nanoparticles up to ~ 100 nm in size (red curve). The low-field line with g = 4.26 corresponds to NV⁻ centers. Microwave frequency 9.4006 GHz.

Fig.2. XPS spectra of acid-purified DNDs: N1s photoemission peaks before (a) and after Ar ion etching (b).

Fig.3. Raman spectrum of DNDs after acid purification and air treatment at 430 °C; wavenumbers of the Raman bands are shown. Excitation wavelength 325 nm. The spectrum is decomposed into six components, where the bands at 1323 and 1590 cm⁻¹ come from sp³ coordinated carbons of DND particles with mean size of ~5 nm and sp² phase, respectively, while the bands centered at ~1745, ~1650 and ~1300 cm⁻¹ are assigned to the contribution of surface carbonyl, hydroxyl groups and fraction of diamond particles with sizes less than 3 nm, correspondingly. Weak shoulder at ~1100 cm⁻¹ comes from transpolyacetylene chains.

Fig.4. 2D- mapping of PL signal intensity of DND spin-coated on a glass microscope coverslip (a) and photoluminescence spectrum (b) of the selected aggregate of detonation nanodiamonds surrounded by a circle in (a). Laser excitation at 532 nm wavelength (100 μ W excitation power). Integration time on the spectrometer CCD is 60 s. The shape of this PL spectrum is consistent with the contribution of both NV⁻ and NV⁰ photoluminescence although we cannot identify their characteristic zero-phonon lines.

Fig.5. Photoluminescence intensity versus time for the DND surrounded by a circle in Fig. 4 (scan), in the presence or absence of an external magnetic field. Excitation laser wavelength: 532 nm, power: 100 μ W. The laser is focused on the nanodiamond. In absence of external magnetic field (*B*=0) we observe only small changes of intensity, that might be due to the blinking of some of the NV⁻ color centers close to DND surface, and therefore more sensitive to charge state trapping. When we apply a magnetic field by manually approaching a permanent magnet at a distance from the sample at which the field amplitude is ~900 G, we observe a large decrease of the PL intensity.

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Figure 1





Figure 2



Figure 3



Figure 4



Figure 5